

# 74VHC27 Triple 3-Input NOR Gate

### Features

- High speed: t<sub>PD</sub> = 4.1ns (typ) at T<sub>A</sub> = 25°C
- Low power dissipation:  $I_{CC} = 2\mu A$  (max) at  $T_A = 25^{\circ}C$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\% V_{CC}$  (min.)
- Power down protection is provided on all inputs
- Low noise: V<sub>OLP</sub> = 0.8V (max.)
- Pin and function compatible with 74HC27

### **General Description**

The VHC27 is an advanced high speed CMOS 3-Input NOR Gate fabricated with silicon gate CMOS technology. It achieves the high-speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

The internal circuit is composed of 3 stages including buffer output, which provide high noise immunity and stable output. An input protection circuit insures that 0V to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery backup. This circuit prevents device destruction due to mismatched supply and input voltages.

### **Ordering Information**

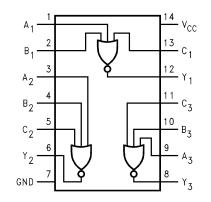
Order Number	Package Number	Package Description
74VHC27M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC27MX_NL <sup>(1)</sup>	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74VHC27SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74VHC27MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering number. Pb-Free package per JEDEC J-STD-020B.

#### Note:

1. Device available in Tape and Reel only.

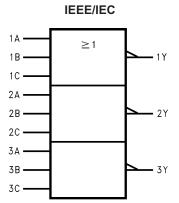
### **Connection Diagram**



## **Pin Descriptions**

Pin Names	Description
A <sub>n</sub> , B <sub>n</sub> , C <sub>n</sub>	Inputs
Y <sub>n</sub>	Outputs

Logic Symbol



## **Truth Table**

Α	В	С	Y
Н	Х	Х	L
Х	Н	Х	L
Х	Х	Н	L
L	L	L	Н

X = Don't Care

### **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	-0.5V to +7.0V
V <sub>IN</sub>	DC Input Voltage	-0.5V to +7.0V
V <sub>OUT</sub>	DC Output Voltage	–0.5V to V <sub>CC</sub> + 0.5V
I <sub>IK</sub>	Input Diode Current	–20mA
I <sub>OK</sub>	Output Diode Current	±20mA
I <sub>OUT</sub>	DC Output Current	±25mA
I <sub>CC</sub>	DC V <sub>CC</sub> /GND Current	±50mA
T <sub>STG</sub>	Storage Temperature	–65°C to +150°C
TL	Lead Temperature (Soldering, 10 seconds)	260°C

## Recommended Operating Conditions<sup>(2)</sup>

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Rating
V <sub>CC</sub>	Supply Voltage	2.0V to +5.5V
V <sub>IN</sub>	Input Voltage	0V to +5.5V
V <sub>OUT</sub>	Output Voltage	0V to V <sub>CC</sub>
T <sub>OPR</sub>	Operating Temperature	–40°C to +85°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time,	
	$V_{CC} = 3.3V \pm 0.3V$	0ns/V ~ 100ns/V
	$V_{CC} = 5.0V \pm 0.5V$	0ns/V ~ 20ns/V

Note:

2. Unused inputs must be held HIGH or LOW. They may not float.

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Symbol Pa					<b>T</b> <sub>A</sub> =					
					25°C		–40°C to +85°C		1	
	Parameter	meter V <sub>CC</sub> (V)	Conditions		Min.	Тур.	Max.	Min.	Max.	Units
V <sub>IH</sub>	HIGH Level	2.0			1.50			1.50		V
	Input Voltage	3.0–5.5	-		0.7 x V <sub>CC</sub>			$0.7 \mathrm{x} \mathrm{V}_{\mathrm{CC}}$		
V <sub>IL</sub>	LOW Level	2.0					0.50		0.50	V
	Input Voltage	3.0–5.5					0.3 x V <sub>CC</sub>		$0.3 \times V_{CC}$	
V <sub>OH</sub>	HIGH Level	2.0	$V_{IN} = V_{IH}$	Ι <sub>ΟΗ</sub> = –50μΑ	1.9	2.0		1.9		V
Output Voltage	3.0	or V <sub>IL</sub>		2.9	3.0		2.9			
	4.5			4.4	4.5		4.4			
	3.0	-	$I_{OH} = -4mA$	2.58			2.48			
		4.5		I <sub>OH</sub> =8mA	3.94			3.80		
V <sub>OL</sub> LOW Level	2.0	$V_{IN} = V_{IH}$	$I_{OL} = 50 \mu A$		0.0	0.1		0.1	V	
	Output Voltage	3.0	or V <sub>IL</sub>			0.0	0.1		0.1	
voltage	4.5				0.0	0.1		0.1		
	3.0		$I_{OL} = 4mA$			0.36		0.44		
		4.5	-	I <sub>OL</sub> = 8mA			0.36		0.44	
I <sub>IN</sub>	Input Leakage Current	0–5.5	$V_{IN} = 5.5V$	or GND			±0.1		±1.0	μA
I <sub>CC</sub>	Quiescent Supply Current	5.5	$V_{IN} = V_{CC} c$	or GND			2.0		20.0	μA

## **Noise Characteristics**

				T <sub>A</sub> =	= 25°C	
Symbol	Parameter	V <sub>CC</sub> (V)	Conditions	Тур.	Limits	Units
V <sub>OLP</sub> <sup>(3)</sup>	Quiet Output Maximum Dynamic V <sub>OL</sub>	5.0	$C_L = 50 pF$	0.3	0.8	V
V <sub>OLV</sub> <sup>(3)</sup>	Quiet Output Minimum Dynamic V <sub>OL</sub>	5.0	$C_L = 50 pF$	-0.3	-0.8	V
V <sub>IHD</sub> <sup>(3)</sup>	Minimum HIGH Level Dynamic Input Voltage	5.0	$C_L = 50 pF$		3.5	V
V <sub>ILD</sub> <sup>(3)</sup>	Maximum LOW Level Dynamic Input Voltage	5.0	$C_L = 50 pF$		1.5	V

#### Note:

3. Parameter guaranteed by design.

## **AC Electrical Characteristics**

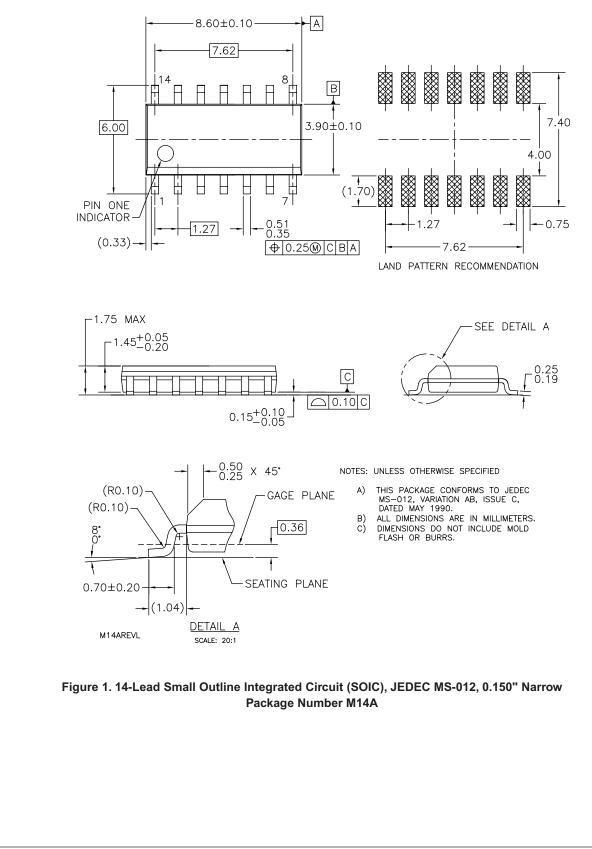
				T,	<sub>A</sub> = 25°	С	T <sub>A</sub> = -40°0	C to +85°C	
Symbol	Parameter	$V_{CC}(V)$	Conditions	Min.	Тур.	Max.	Min.	Max.	Units
t <sub>PHL</sub> , t <sub>PLH</sub>	Propagation Delay	3.3 ± 0.3	$C_L = 15 pF$		6.2	8.8	1.0	10.5	ns
			$C_L = 50 pF$		8.7	12.3	1.0	14.0	
		5.0 ± 0.5	$C_L = 15 pF$		4.1	5.9	1.0	7.0	ns
			$C_L = 50 pF$		5.6	7.9	1.0	9.0	
C <sub>IN</sub>	Input Capacitance		V <sub>CC</sub> = Open		4	10		10	pF
C <sub>PD</sub>	Power Dissipation Capacitance		(4)		20				pF

Note:

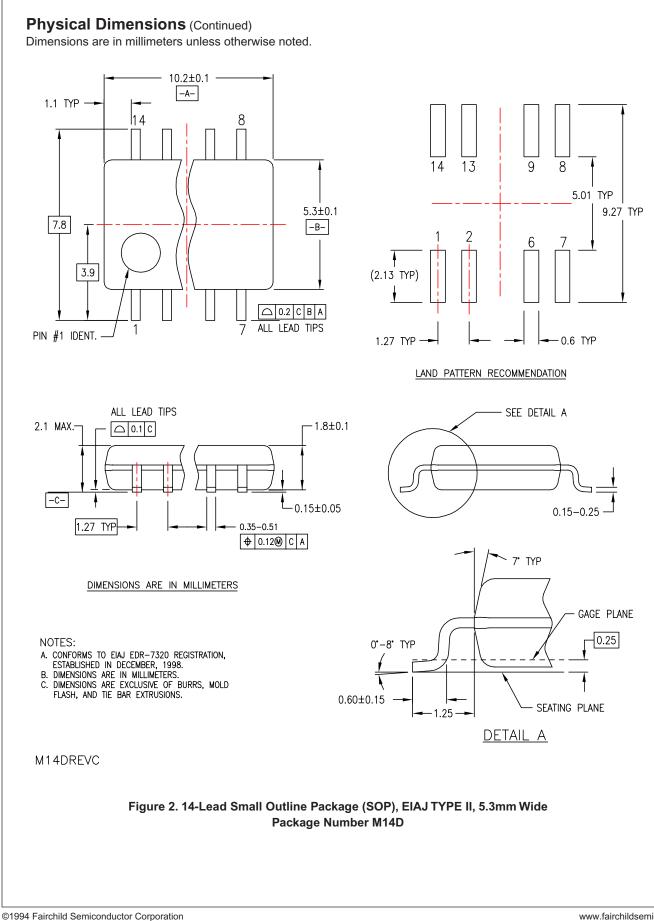
4.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC}$  (opr.) =  $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 3$  (per gate).

### **Physical Dimensions**

Dimensions are in inches (millimeters) unless otherwise noted.



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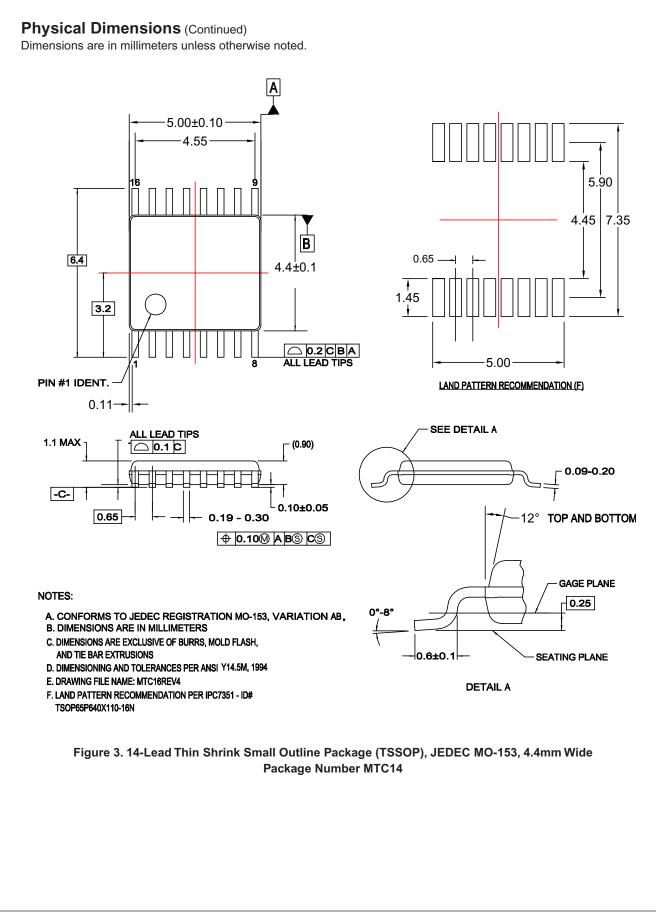


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